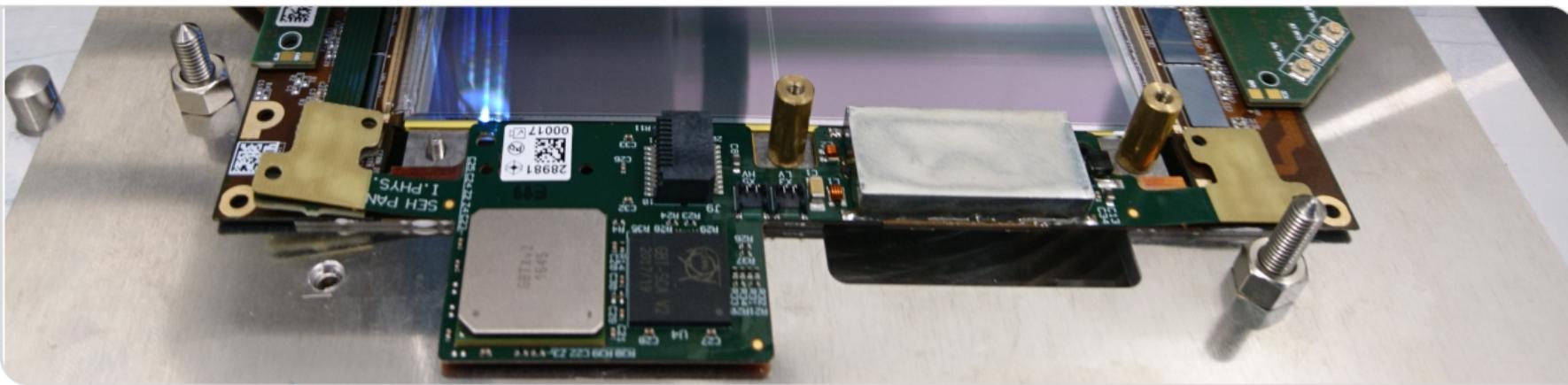


# Beam Test of Silicon Sensor Modules with Irradiated Sensors for the CMS Experiment

T 60.7

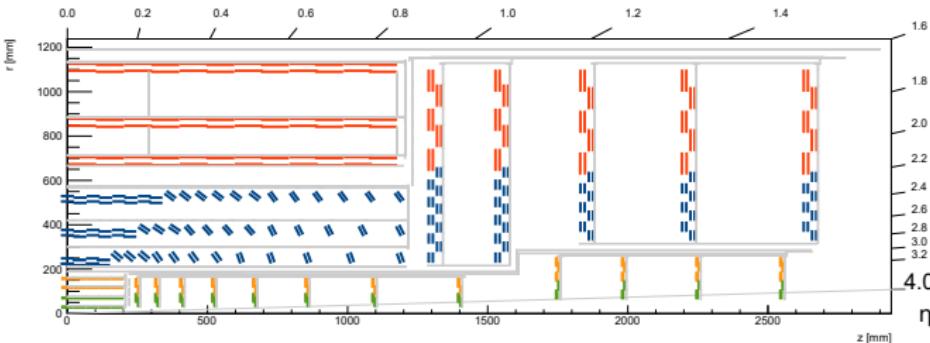
Tobias Barvich, Justus Braach, Alexander Dierlamm, Ulrich Husemann, **Roland Koppenhöfer**, Stefan Maier, Thomas Müller, Marius Neufeld, Andreas Nürnberg, Hans Jürgen Simonis, Julian Stanulla, Pia Steck, Florian Wittig | March 17, 2021



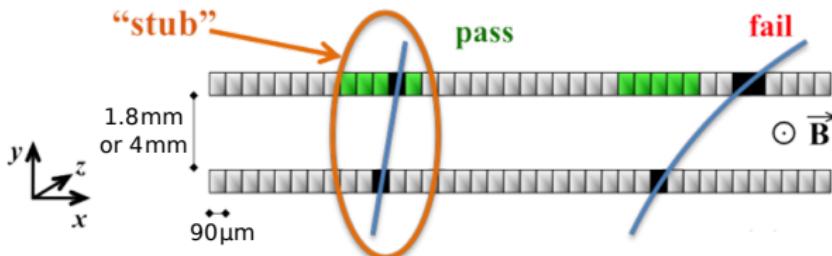
# The Phase-2 Upgrade of the CMS Outer Tracker

# Phase-2 Upgrade of the CMS Outer Tracker

- New silicon tracker in the CMS experiment for HL-LHC by 2027
- Requirements for the Outer Tracker upgrade:
  - Improved radiation tolerance up to  $1 \times 10^{15} \text{ n}_{\text{eq}} \text{ cm}^{-2}$
  - Increased granularity
  - Improved two-track separation
  - Reduced material in tracking volume
  - Contribution to L1 trigger
- Silicon sensors in tracker modules will be operated at about  $-20^\circ\text{C}$



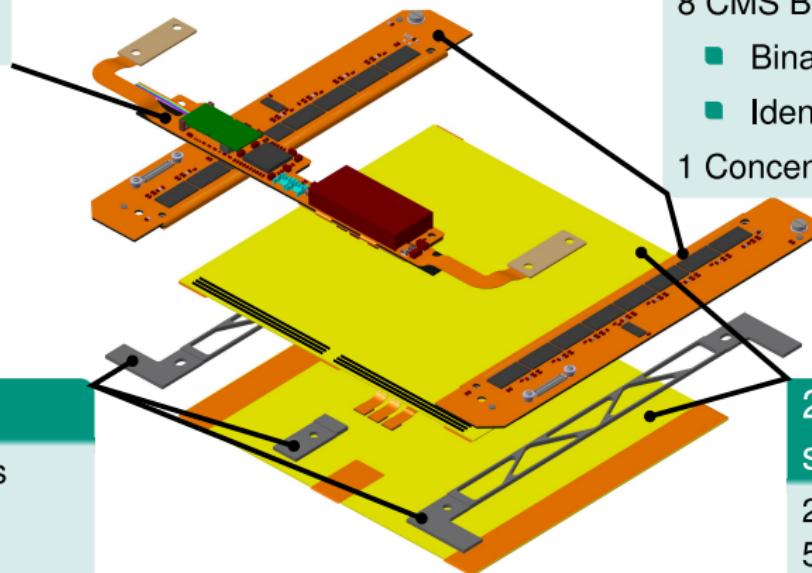
2S modules and PS modules in the Phase-2 Outer Tracker



# 2S Module for the CMS Outer Tracker

## Service Hybrid

Powering  
Data transmission



## 2 Front-end Hybrids

8 CMS Binary Chips<sup>2</sup> each

- Binary readout of sensor signals
- Identification of stubs

1 Concentrator Chip each

## AI-CF<sup>1</sup> Spacer

Spacing between sensors  
Main cooling path  
Mechanical fixation

## 2 parallel silicon strip sensors

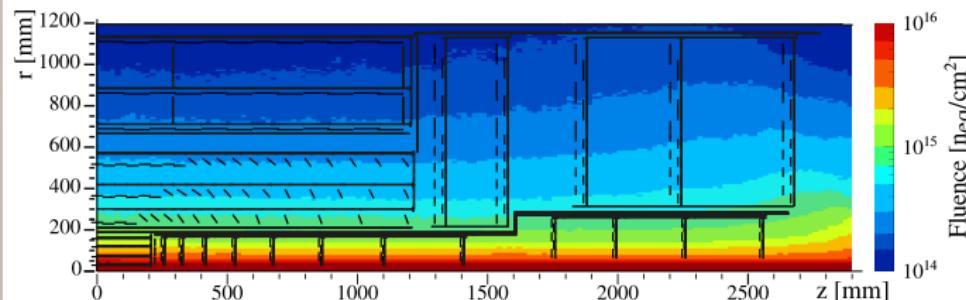
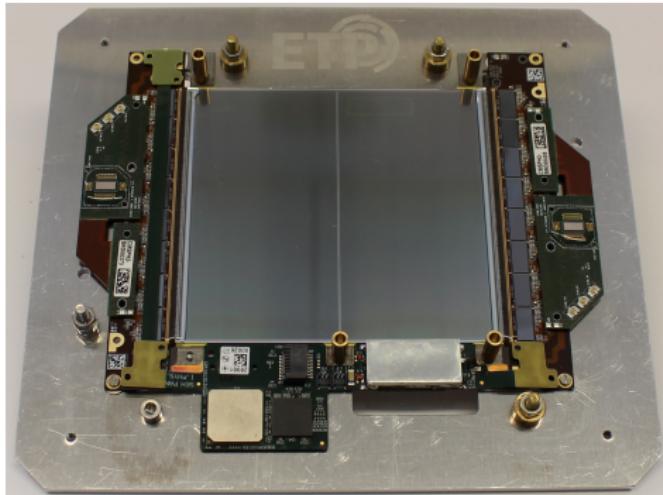
2 × 1016 strips each  
5 cm length, 90 µm pitch

<sup>1</sup> Aluminum / carbon fiber composite

<sup>2</sup> Prydderch et al., *CBC3: a CMS microstrip readout ASIC with logic for track-trigger modules at HL-LHC*, CMS-CR-2017-383

# 2S Module Prototype with Irradiated Sensors

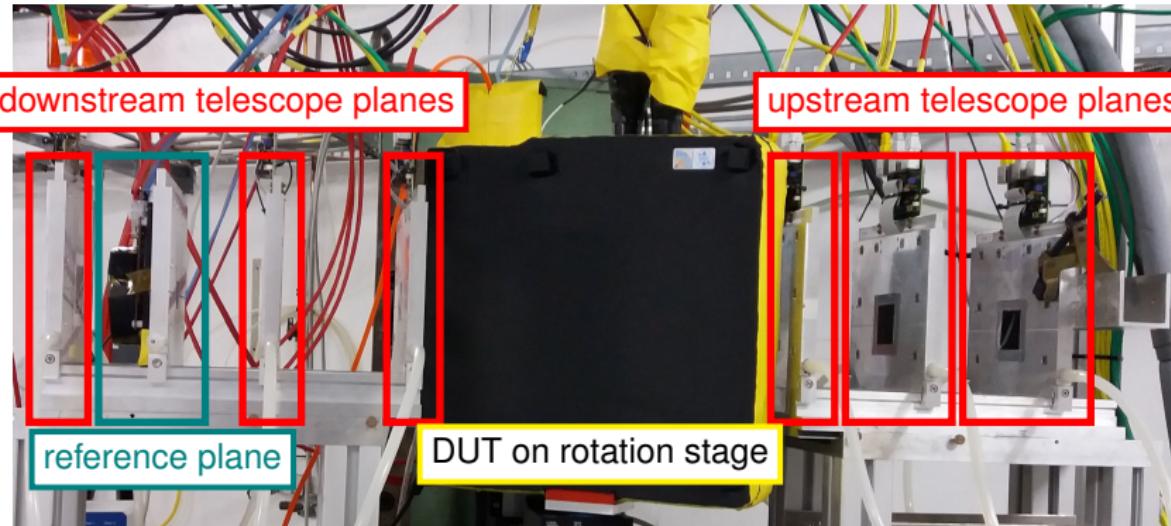
- Study performance of 2S modules after 10 years of operation in CMS
- Expected maximum 2S module fluence for  $4000 \text{ fb}^{-1}$ : approximately  $5 \times 10^{14} \text{ n}_{\text{eq}}/\text{cm}^2$
- Irradiated 2S sensors before module assembly with 23 MeV protons at KIT to  $4.6 \times 10^{14} \text{ n}_{\text{eq}}/\text{cm}^2$
- CMS tracker operated cold, but short phases of warming up needed and desired  
→ Different equivalent annealing times for **top** and **bottom** sensor: **10 d@RT** and **200 d@RT**



# Beam Test of 2S Module with Irradiated Sensors

# Experimental Setup

- One week of beam time at DESY Beam Test Facility (August 2020)
- 2S modules cooled down to  $\approx -17^{\circ}\text{C}$  sensor temperature



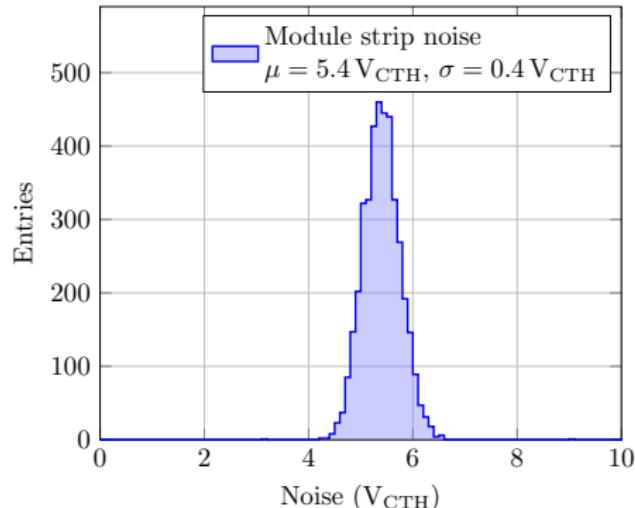
# Measurement Program and Module Noise

## Measurement Program:

- Threshold scans at different bias voltages  
→ study hit and stub detection efficiency
- Angular scans at different bias voltages  
→ study stub resolution by mimicking bent particle incidence
- Bias voltage scan

## 2S Module Noise:

- CMS Binary Chip strip noise at  $\approx 850 \text{ e}^-$  at  $T_{\text{sensor}} \approx -17^\circ\text{C}$
- Noise comparable with results of unirradiated 2S modules at room temperature

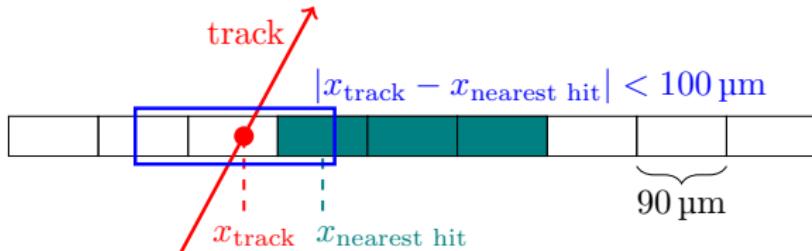


conversion factor:  $1 \text{ V}_{\text{CTH}} = 156 \text{ e}^-$

# Definition of Efficiencies

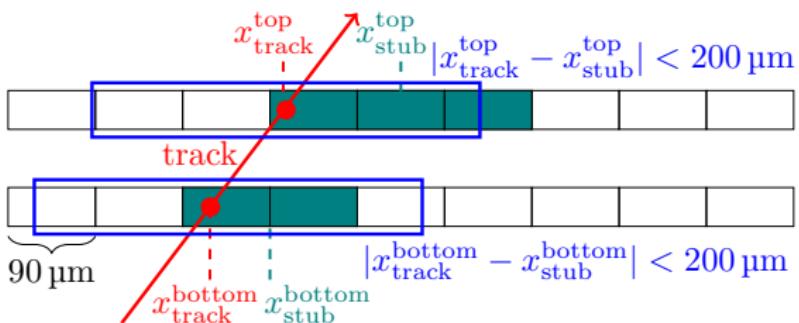
## Hit Efficiency: "nearest hit"

- Evaluated for individual sensors
- Track to hit matching for  $|x_{\text{track}} - x_{\text{nearest hit}}| < 100 \mu\text{m}$



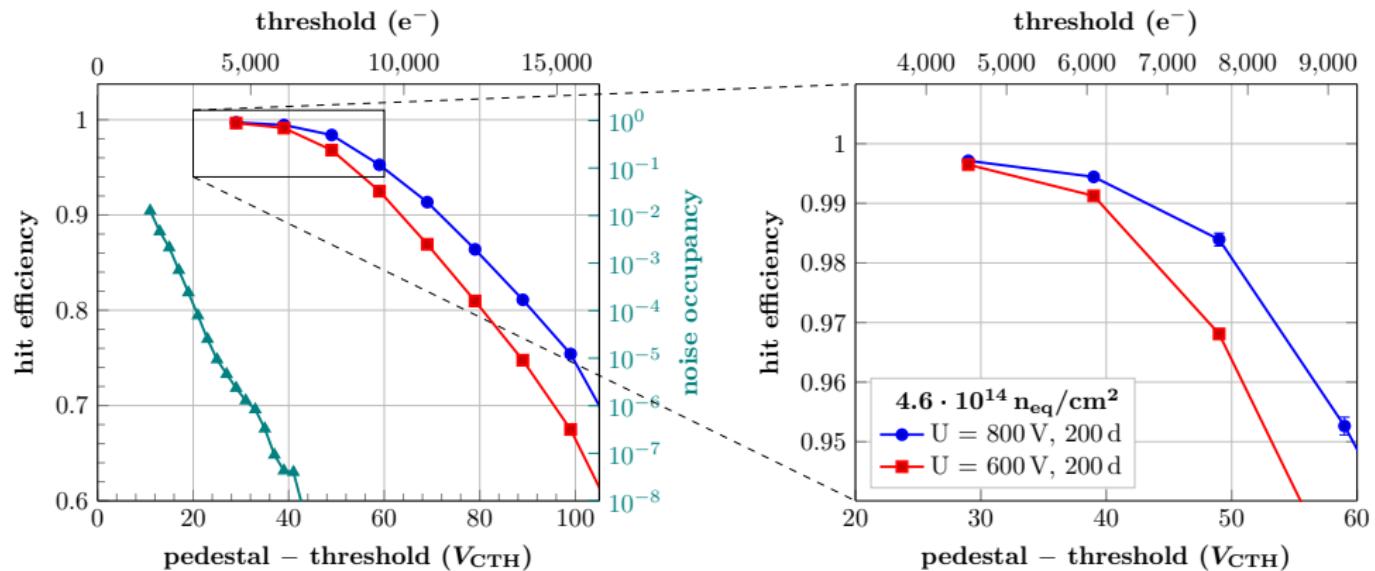
## Stub Efficiency:

- Evaluated for combined sensors
- Track to stub matching for  $|x_{\text{track}}^{\text{bottom}} - x_{\text{stub}}^{\text{bottom}}| < 200 \mu\text{m}$   
and  $|x_{\text{track}}^{\text{top}} - x_{\text{stub}}^{\text{top}}| < 200 \mu\text{m}$



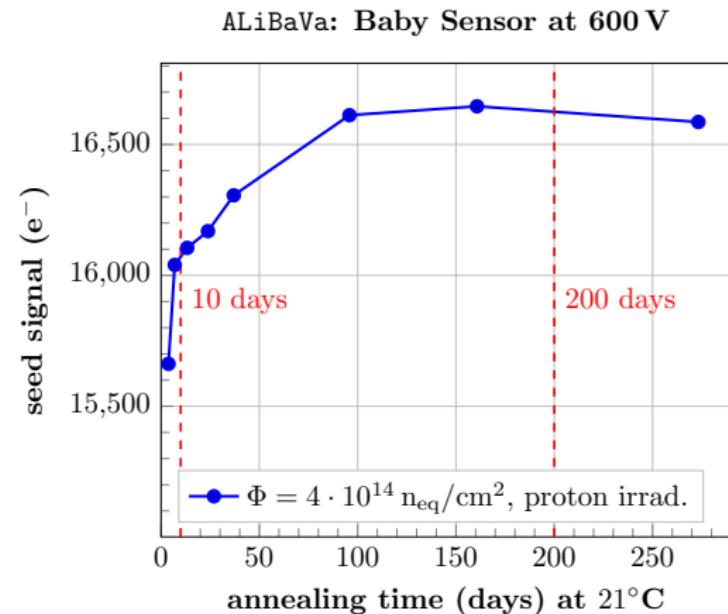
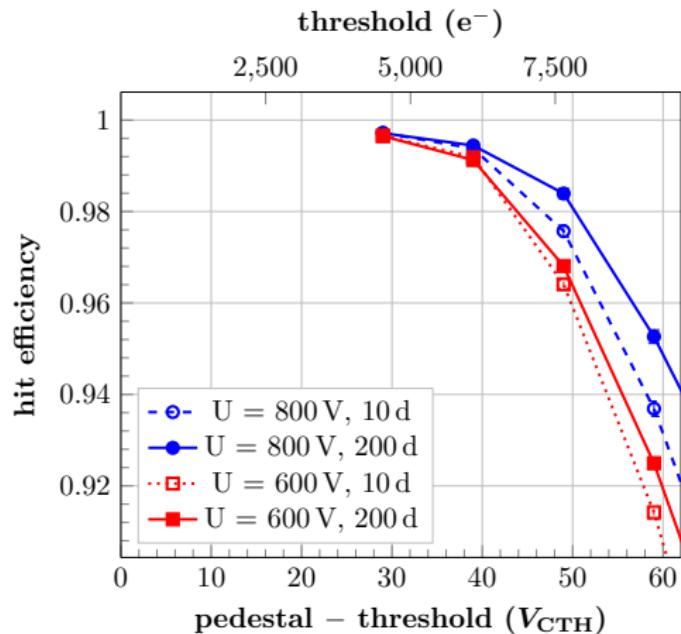
# Threshold Scan at Different Bias Voltages

- Data for perpendicular beam incidence
- Up to threshold of  $6000 \text{ e}^-$  sensor efficient with more than 99% at 600 V
- Noise occupancy below  $10^{-5}$  for all threshold scan data points
- Increasing voltage to 800 V yields small increase in efficiency



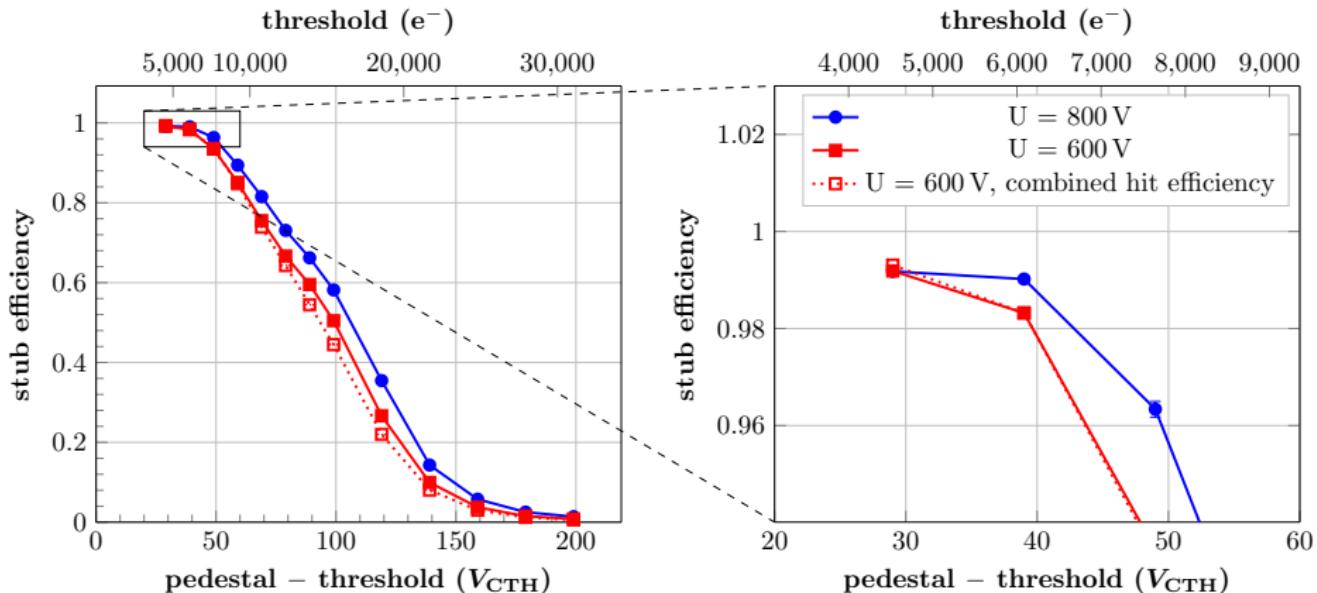
# Threshold Scan at Different Annealing States

- Sensor with 200 d of annealing slightly more efficient
- Compatible with signal measurements of proton irradiated sensors using analogue readout (ALiBaVa)



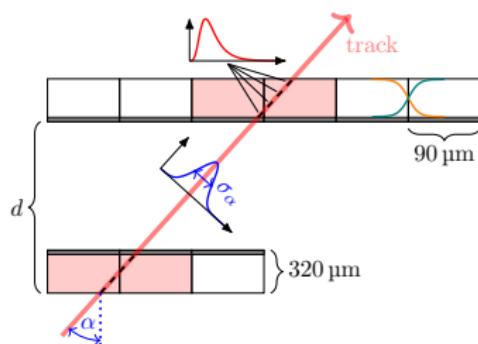
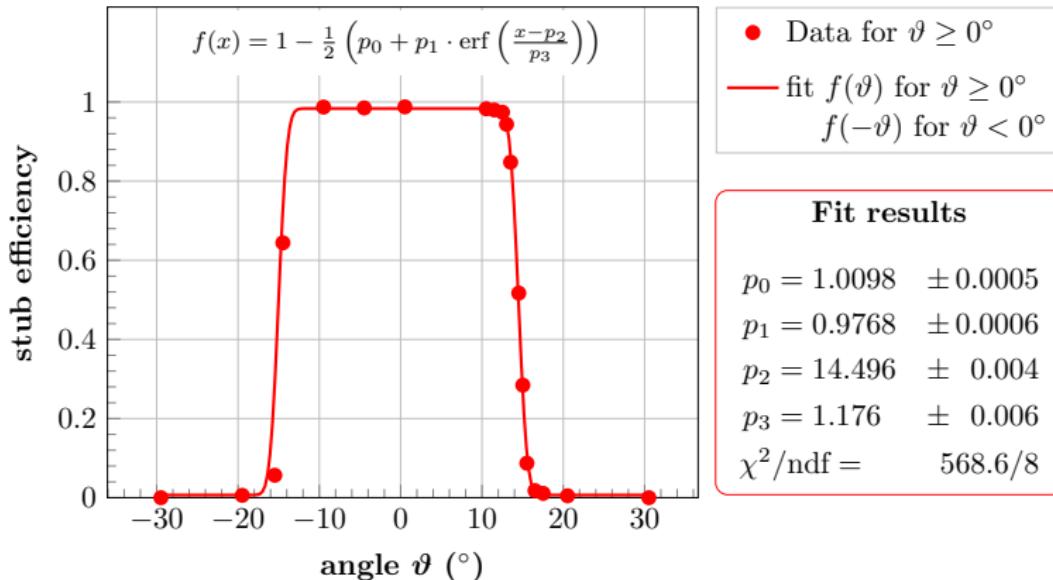
# Module Stub Efficiency – Threshold Scan

- Data for perpendicular beam incidence
- Module stub efficiency of more than 98% at 600 V and nominal threshold
- Stub efficiency compatible with combined sensor hit efficiency



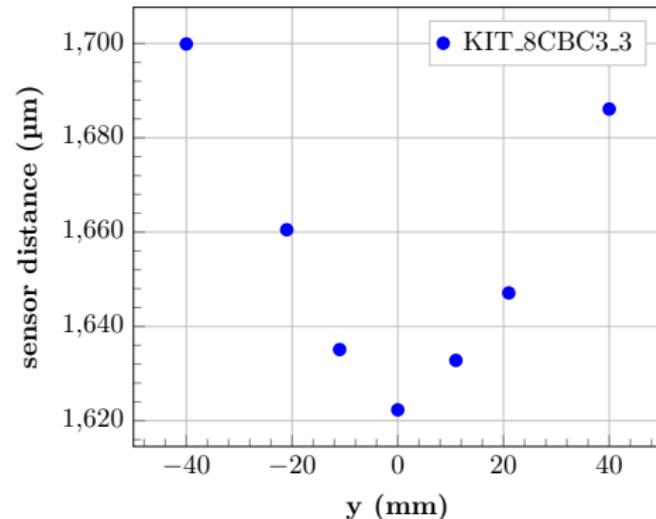
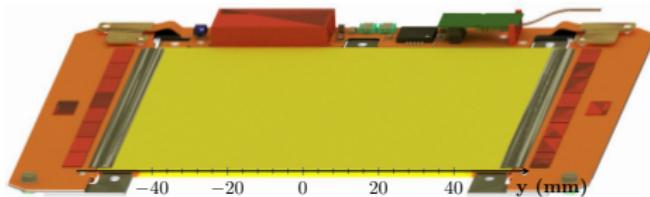
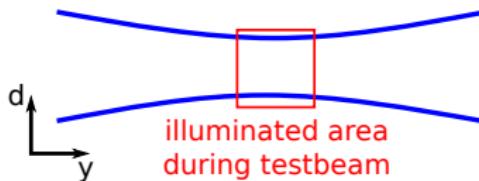
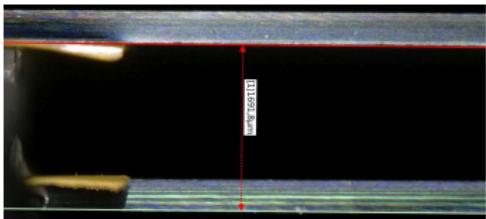
# Module Stub Efficiency – Angular Scan

- Stub window set to  $\pm 4.5$  strips,  $U = 600$  V
- Geometrical expectation of module design with  $d = 1.68$  mm leads to  $p_2 \approx 13.9^\circ$   
 → deviation explained by varying sensor distance along module side (s. next slide)



# Measurement of 2S Module Sensor Distances

- Sensor distance measured using microscope along hybrid-free module side
- Measurement uncertainty approximately  $\pm 10 \mu\text{m}$
- Sensor distance shows relative bow of  $\approx 80 \mu\text{m}$
- Area  $-4 \text{ mm} \leq x \leq 6 \text{ mm}$  illuminated during angular scans  
 $\Rightarrow d = 1.625 \text{ mm}$  leads to  $p_2 \approx 14.49^\circ$   
 $\Rightarrow$  consistent with testbeam data



- Successfully performed 2S module beam test with irradiated sensors up to  $4.6 \cdot 10^{14} n_{eq}/cm^2$
- Modules show high efficiencies and low noise occupancy at nominal bias voltage (600 V)
  - Hit efficiency of more than 99% for noise occupancy less than  $10^{-5}$
  - Stub efficiency of more than 98%
- Efficiency comparison between different annealing states coincides with analogue signal measurements
- Angular scan proves stub logic functionality
- Measured stub efficiency turn-on angle corresponds to expectation taking into account measured module prototype sensor distance

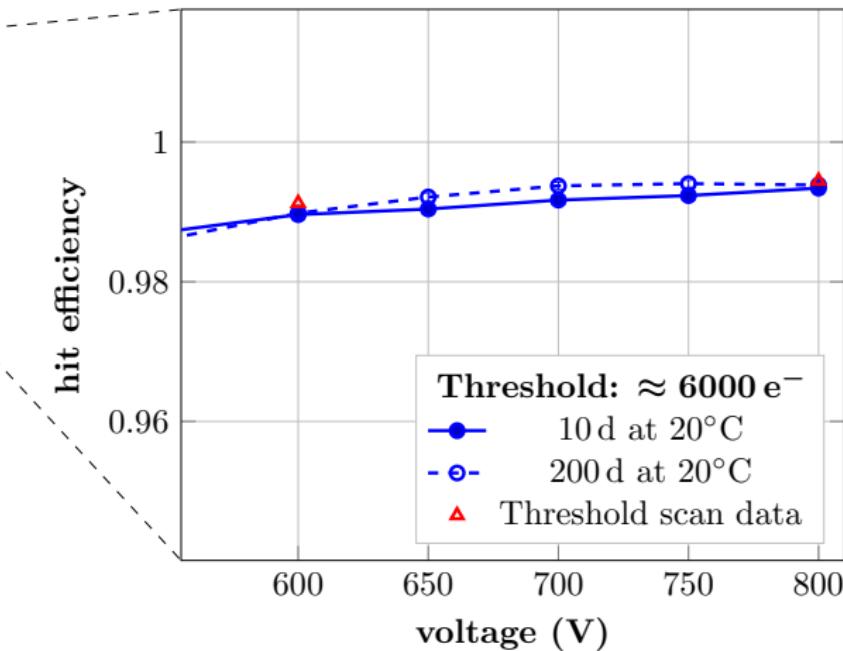
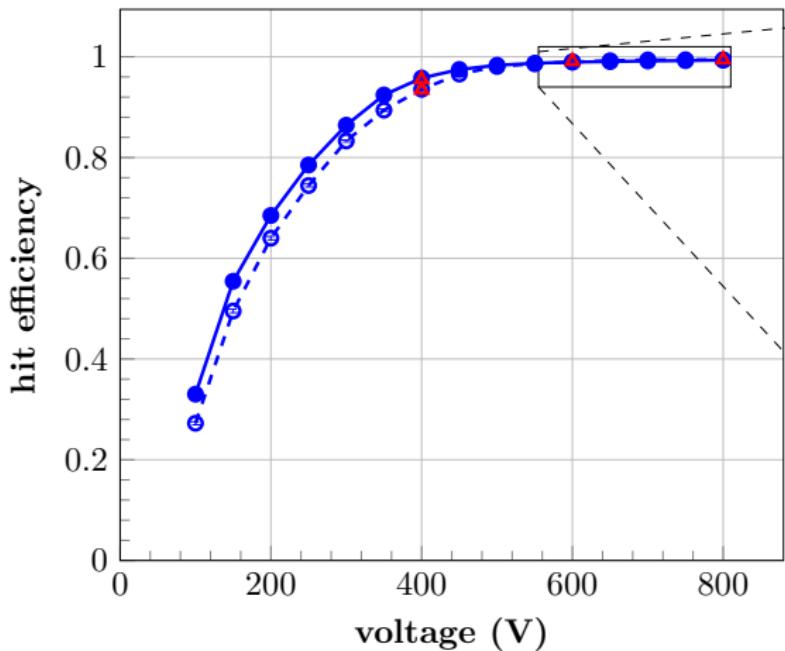
## Outlook:

- Finalise testbeam analysis
- CMS Detector Note and Publication together with results from unirradiated 2S module testbeams in preparation

# Backup

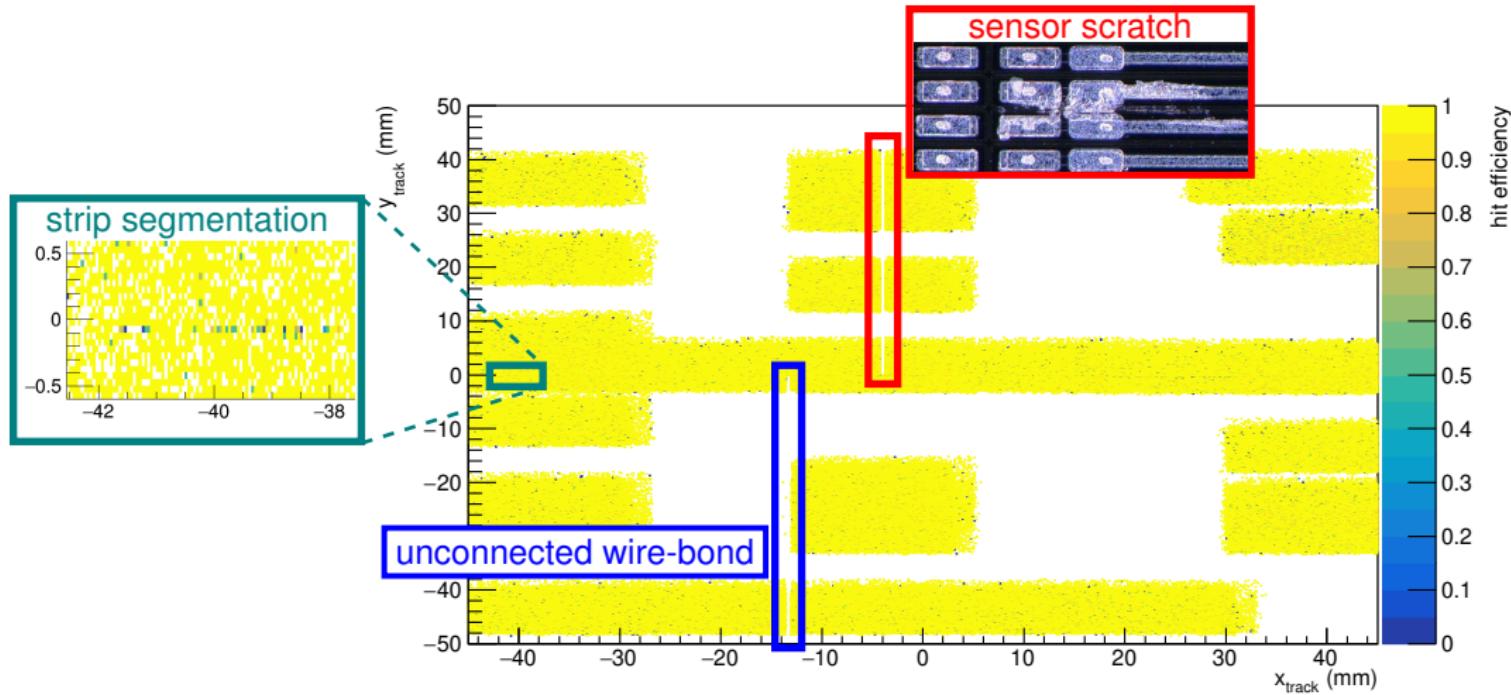
# Bias Scan

- Depleted region and thus efficiency grows with bias voltage
- Data consistent with threshold scan results



# Bottom Sensor Hit Efficiency

- Sensors efficient in illuminated areas, previously detected defects during functional testing are masked



# Inpixel-Efficiencies

